# Quad 2-Channel Analog Multiplexer/Demultiplexer

The MC14551B is a digitally-controlled analog switch. This device implements a 4PDT solid state switch with low ON impedance and very low OFF Leakage current. Control of analog signals up to the complete supply voltage range can be achieved.

#### **Features**

- Triple Diode Protection on All Control Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Analog Voltage Range (V<sub>DD</sub> V<sub>EE</sub>) = 3.0 to 18 V
   Note: V<sub>EE</sub> must be ≤ V<sub>SS</sub>
- Linearized Transfer Characteristics
- Low Noise 12 nV $\sqrt{\text{Cycle}}$ ,  $f \ge 1.0$  kHz typical
- For Low R<sub>ON</sub>, Use The HC4051, HC4052, or HC4053 High–Speed CMOS Devices
- Switch Function is Break Before Make
- These Devices are Pb-Free and are RoHS Compliant
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

#### **MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
DC Supply Voltage Range (Referenced to V <sub>EE</sub> , V <sub>SS</sub> ≥ V <sub>EE</sub> )	V <sub>DD</sub>	- 0.5 to + 18.0	V
Input or Output Voltage (DC or Transient) (Referenced to V <sub>SS</sub> for Control Input and V <sub>EE</sub> for Switch I/O)	V <sub>in</sub> , V <sub>out</sub>	– 0.5 to V <sub>DD</sub> + 0.5	<b>V</b>
Input Current (DC or Transient), per Control Pin	l <sub>in</sub>	± 10	mA
Switch Through Current	I <sub>sw</sub>	± 25	mA
Power Dissipation, per Package (Note 1)	P <sub>D</sub>	500	mW
Ambient Temperature Range	T <sub>A</sub>	- 55 to + 125	°C
Storage Temperature Range	T <sub>stg</sub>	- 65 to + 150	°C
Lead Temperature (8–Second Soldering)	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 Temperature Derating: Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$  for control inputs and  $V_{EE} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$  for Switch I/O.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$ ,  $V_{EE}$  or  $V_{DD}$ ). Unused outputs must be left open.



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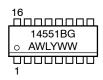
#### MARKING DIAGRAMS 16 ኬ ላ ላ ላ ላ ላ



PDIP-16 P SUFFIX CASE 648 16 hhhhhhhhhhh MC14551BCP O AWLYYWWG PUUUUUUU



SOIC-16 D SUFFIX CASE 751B



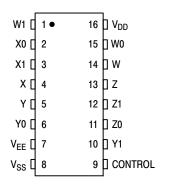
A = Assembly Location

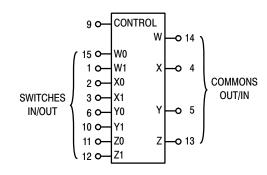
WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G = Pb-Free Package

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### **PIN ASSIGNMENT**





$V_{DD} = Pin 16$
$V_{SS} = Pin 8$
$V_{EE}$ = Pin 7

Control	ON					
0	W0 X0 Y0 Z0					
1	W1 X1 Y1 Z1					

NOTE: Control Input referenced to V<sub>SS</sub>, Analog Inputs and Outputs reference to V<sub>EE</sub>. V<sub>EE</sub> must be  $\leq$  V<sub>SS</sub>.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC14551BCPG	PDIP-16 (Pb-Free)	25 Units / Rail
MC14551BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14551BDR2G	SOIC-16	OFOO / Tono & Dool
NLV14551BDR2G*	(Pb-Free)	2500 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

#### **ELECTRICAL CHARACTERISTICS**

(Channel Off)

				- 5	55°C 25°C 125°C		125°C				
Characteristic	V <sub>DD</sub>	Test Conditions	Symbol	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
SUPPLY REQUIREMENTS (	Voltage	es Referenced to V <sub>EE</sub> )			l.	I		I	I	I	
Power Supply Voltage Range	_	$V_{DD} - 3.0 \ge V_{SS} \ge V_{EE}$	V <sub>DD</sub>	3.0	18	3.0	-	18	3.0	18	V
Quiescent Current Per Package	5.0 10 15	$ \begin{array}{l} \text{Control Inputs: V}_{\text{in}} = \\ \text{V}_{\text{SS}} \text{ or V}_{\text{DD}}, \\ \text{Switch I/O: V}_{\text{EE}} \leq \text{V}_{\text{I/O}} \\ \leq \text{V}_{\text{DD}}, \text{ and } \Delta \text{V}_{\text{switch}} \leq \\ \text{500 mV (Note 3)} \end{array} $	I <sub>DD</sub>	- - -	5.0 10 20	- - -	0.005 0.010 0.015	5.0 10 20	- - -	150 300 600	μА
Total Supply Current (Dynamic Plus Quiescent, Per Package)	5.0 10 15	T <sub>A</sub> = 25°C only (The channel component, (V <sub>in</sub> – V <sub>out</sub> )/R <sub>on</sub> , is not included.)	I <sub>D(AV)</sub>			Typical	(0.07 μΑ/ (0.20 μΑ/ (0.36 μΑ/	kHz) f +	$I_{DD}$		μА
CONTROL INPUT (Voltages	Refere	nced to V <sub>SS</sub> )									
Low-Level Input Voltage	5.0 10 15	R <sub>on</sub> = per spec, I <sub>off</sub> = per spec	V <sub>IL</sub>	- - -	1.5 3.0 4.0		2.25 4.50 6.75	1.5 3.0 4.0		1.5 3.0 4.0	٧
High-Level Input Voltage	5.0 10 15	R <sub>on</sub> = per spec, I <sub>off</sub> = per spec	V <sub>IH</sub>	3.5 7.0 11	- - -	3.5 7.0 11	2.75 5.50 8.25	- - -	3.5 7.0 11	- - -	V
Input Leakage Current	15	V <sub>in</sub> = 0 or V <sub>DD</sub>	I <sub>in</sub>	-	±0.1	-	±0.00001	±0.1	-	±1.0	μΑ
Input Capacitance	-		C <sub>in</sub>	_	-	-	5.0	7.5	-	-	pF
SWITCHES IN/OUT AND CO	ОММО	IS OUT/IN — W, X, Y, Z (\	/oltages Re	eferenc	ed to V <sub>E</sub>	:Ε)		•	•	•	
Recommended Peak-to- Peak Voltage Into or Out of the Switch	_	Channel On or Off	V <sub>I/O</sub>	0	V <sub>DD</sub>	0	-	V <sub>DD</sub>	0	V <sub>DD</sub>	V <sub>p-p</sub>
Recommended Static or Dynamic Voltage Across the Switch (Note 3) (Figure 3)	_	Channel On	$\Delta V_{switch}$	0	600	0	-	600	0	300	mV
Output Offset Voltage	-	V <sub>in</sub> = 0 V, No Load	V <sub>OO</sub>	_	-	-	10	_	-	-	μV
ON Resistance	5.0 10 15	$\begin{array}{l} \Delta V_{switch} \leq 500 \text{ mV} \\ \text{(Note 3),} \\ V_{in} = V_{IL} \text{ or } V_{IH} \\ \text{(Control), and } V_{in} = 0 \text{ to} \\ V_{DD} \text{ (Switch)} \end{array}$	R <sub>on</sub>	-	800 400 220	- - -	250 120 80	1050 500 280	- - -	1200 520 300	Ω
ΔON Resistance Between Any Two Channels in the Same Package	5.0 10 15		$\Delta R_{on}$	- - -	70 50 45	- - -	25 10 10	70 50 45	- - -	135 95 65	Ω
Off-Channel Leakage Current (Figure 8)	15	V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub> (Control) Channel to Channel or Any One Channel	I <sub>off</sub>	-	±100	_	±0.05	±100	-	±1000	nA
Capacitance, Switch I/O	-	Switch Off	C <sub>I/O</sub>	_	-	_	10	-	_	-	pF
Capacitance, Common O/I	-		C <sub>O/I</sub>	-	-	-	17	-	-	-	pF
Capacitance, Feedthrough	_	Pins Not Adjacent	C <sub>I/O</sub>	_	-	-	0.15	-	-	-	pF

Pins Adjacent

0.47

Data labeled "Typ" is not to be used for design purposes, but is intended as an indication of the IC's potential performance.
 For voltage drops across the switch (ΔV<sub>switch</sub>) > 600 mV ( > 300 mV at high temperature), excessive V<sub>DD</sub> current may be drawn; i.e. the current out of the switch may contain both V<sub>DD</sub> and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.)

## **ELECTRICAL CHARACTERISTICS** ( $C_L$ = 50 pF, $T_A$ = 25°C, $V_{EE} \leq V_{SS}$ )

Characteristic	Symbol	V <sub>DD</sub> – V <sub>EE</sub> Vdc	Min	Typ (Note 4)	Max	Unit
Propagation Delay Times Switch Input to Switch Output ( $R_L$ = 10 k $\Omega$ ) $t_{PLH}$ , $t_{PHL}$ = (0.17 ns/pF) $C_L$ + 26.5 ns $t_{PLH}$ , $t_{PHL}$ = (0.08 ns/pF) $C_L$ + 11 ns $t_{PLH}$ , $t_{PHL}$ = (0.06 ns/pF) $C_L$ + 9.0 ns	t <sub>PLH</sub> , t <sub>PHL</sub>	5.0 10 15	-	35 15 12	90 40 30	ns
Control Input to Output ( $R_L = 10 \text{ k}\Omega$ ) $V_{EE} = V_{SS}$ (Figure 4)	t <sub>PLH</sub> , t <sub>PHL</sub>	5.0 10 15	-	350 140 100	875 350 250	ns
Second Harmonic Distortion $R_L = 10 \text{ k}\Omega, f = 1 \text{ kHz}, V_{in} = 5 \text{ V}_{p-p}$	_	10	-	0.07	-	%
Bandwidth (Figure 5) $R_L = 1 \text{ k}\Omega, V_{in} = 1/2 (V_{DD} - V_{EE})_{p-p}, \\ 20 \text{ Log } (V_{out}/V_{in}) = -3 \text{ dB, } C_L = 50 \text{ pF}$	BW	10	-	17	-	MHz
Off Channel Feedthrough Attenuation, Figure 5 R <sub>L</sub> = 1 k $\Omega$ , V <sub>in</sub> = 1/2 (V <sub>DD</sub> - V <sub>EE</sub> ) <sub>p-p</sub> , f <sub>in</sub> = 55 MHz	-	10	_	<b>- 50</b>	-	dB
Channel Separation (Figure 6) $R_L = 1 \text{ k}\Omega, V_{in} = 1/2 (V_{DD} - V_{EE})_{p-p}, f_{in} = 3 \text{ MHz}$	-	10	-	<b>- 50</b>	-	dB
Crosstalk, Control Input to Common O/I, Figure 7 R1 = 1 k $\Omega$ , R <sub>L</sub> = 10 k $\Omega$ , Control t <sub>r</sub> = t <sub>f</sub> = 20 ns	-	10	_	75	-	mV

<sup>4.</sup> Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

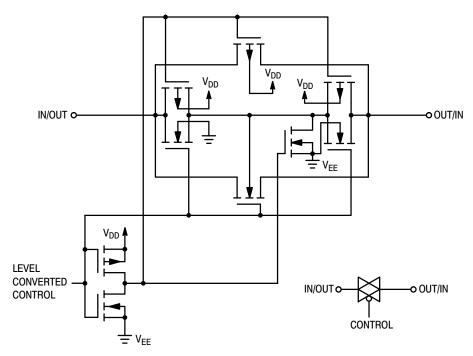


Figure 1. Switch Circuit Schematic

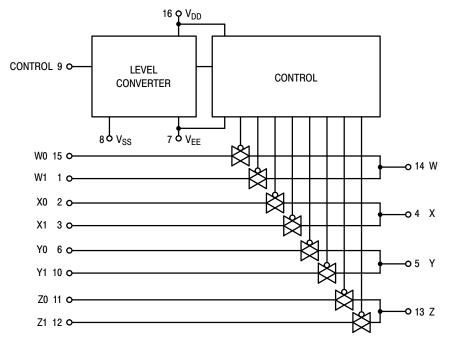


Figure 2. MC14551B Functional Diagram

#### **TEST CIRCUITS**

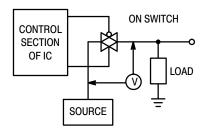


Figure 3.  $\Delta V$  Across Switch

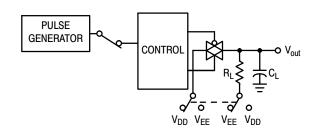


Figure 4. Propagation Delay Times, Control to Output

Control input used to turn ON or OFF the switch under test.

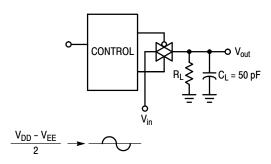


Figure 5. Bandwidth and Off-Channel Feedthrough Attenuation

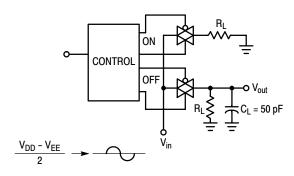


Figure 6. Channel Separation (Adjacent Channels Used for Setup)

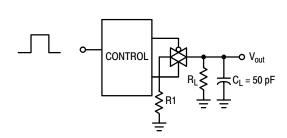


Figure 7. Crosstalk, Control Input to Common O/I

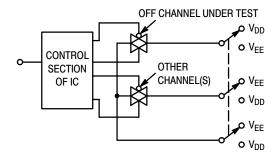


Figure 8. Off Channel Leakage

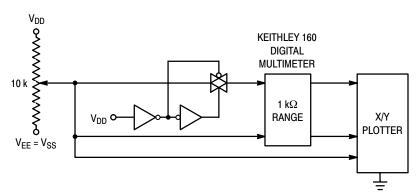


Figure 9. Channel Resistance (R<sub>ON</sub>) Test Circuit

#### TYPICAL RESISTANCE CHARACTERISTICS

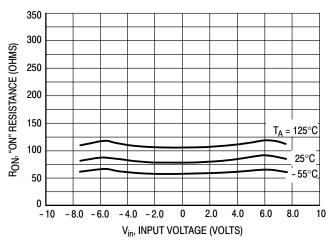


Figure 10.  $V_{DD}$  @ 7.5 V,  $V_{EE}$  @ – 7.5 V

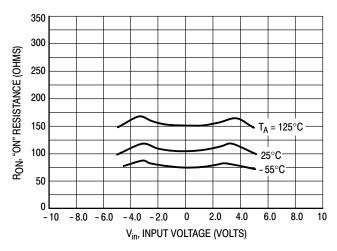


Figure 11. V<sub>DD</sub> @ 5.0 V, V<sub>EE</sub> @ – 5.0 V

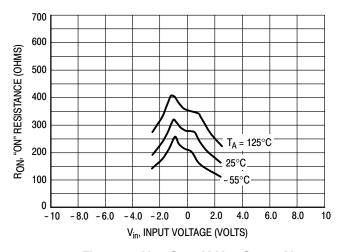


Figure 12.  $V_{DD}$  @ 2.5 V,  $V_{EE}$  @ – 2.5 V

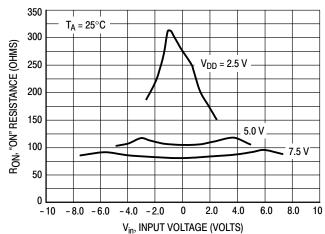


Figure 13. Comparison at 25  $^{\circ}$  C,  $V_{DD}$  @ –  $V_{EE}$ 

#### **APPLICATIONS INFORMATION**

Figure A illustrates use of the on–chip level converter detailed in Figure 2. The 0–to–5.0 V Digital Control signal is used to directly control a 9  $V_{p-p}$  analog signal.

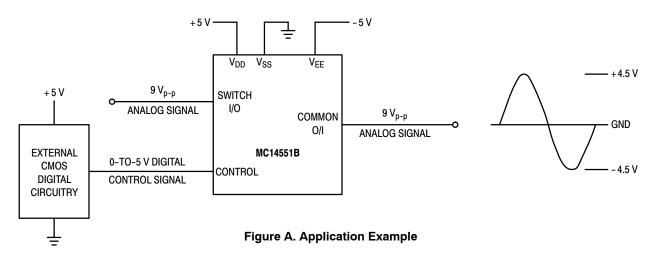
The digital control logic levels are determined by  $V_{DD}$  and  $V_{SS}$ . The  $V_{DD}$  voltage is the logic high voltage; the  $V_{SS}$  voltage is logic low. For the example,  $V_{DD} = +5.0 \text{ V} = \text{logic}$  high at the control inputs;  $V_{SS} = \text{GND} = 0 \text{ V} = \text{logic}$  low.

The maximum analog signal level is determined by  $V_{DD}$  and  $V_{EE}$ . The  $V_{DD}$  voltage determines the maximum recommended peak above  $V_{SS}$ . The  $V_{EE}$  voltage determines the maximum swing below  $V_{SS}$ . For the example,  $V_{DD} - V_{SS} = 5.0 \text{ V}$  maximum swing above  $V_{SS}$ ;  $V_{SS} - V_{EE} = 5.0 \text{ V}$  maximum swing below  $V_{SS}$ . The example shows a  $\pm 4.5 \text{ V}$ 

signal which allows a 1/2 V margin at each peak. If voltage transients above  $V_{DD}$  and/or below  $V_{EE}$  are anticipated on the analog channels, external diodes  $(D_x)$  are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The absolute maximum potential difference between  $V_{DD}$  and  $V_{EE}$  is 18 V. Most parameters are specified up to 15 V which is the recommended maximum difference between  $V_{DD}$  and  $V_{EE}$ .

Balanced supplies are not required. However,  $V_{SS}$  must be greater than or equal to  $V_{EE}$ . For example,  $V_{DD}$  = + 10 V,  $V_{SS}$  = + 5.0 V, and  $V_{EE}$  = - 3.0 V is acceptable. See the table below.



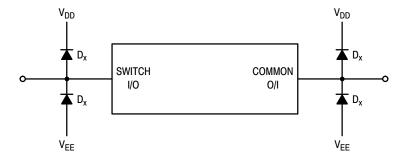


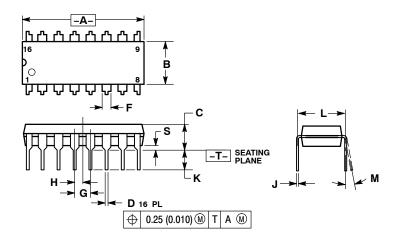
Figure B. External Schottky or Germanium Clipping Diodes

#### POSSIBLE SUPPLY CONNECTIONS

V <sub>DD</sub> In Volts	V <sub>SS</sub> In Volts	V <sub>EE</sub> In Volts	Control Inputs Logic High/Logic Low In Volts	Maximum Analog Signal Range In Volts
+ 8	0	- 8	+ 8/0	+ 8 to - 8 = 16 V <sub>p-p</sub>
+ 5	0	<b>- 12</b>	+ 5/0	+ 5 to - 12 = 17 V <sub>p-p</sub>
+ 5	0	0	+ 5/0	+ 5 to 0 = 5 V <sub>p-p</sub>
+ 5	0	<b>- 5</b>	+ 5/0	+ 5 to - 5 = 10 V <sub>p-p</sub>
+ 10		<b>- 5</b>	+ 10/ + 5	+ 10 to – 5 = 15 V <sub>p-p</sub>

#### **PACKAGE DIMENSIONS**

PDIP-16 CASE 648-08 ISSUE T



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

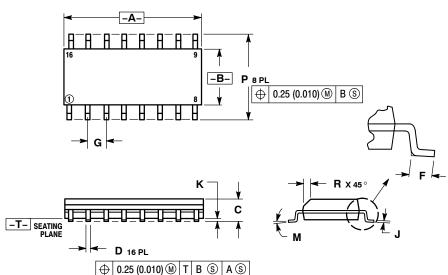
  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

  5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.740	0.770	18.80	19.55
В	0.250	0.270	6.35	6.85
С	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100	BSC	2.54	BSC
Н	0.050	BSC	1.27	BSC
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0°	10 °	0°	10 °
S	0.020	0.040	0.51	1.01

#### PACKAGE DIMENSIONS

#### SOIC-16 **D SUFFIX** CASE 751B-05 ISSUE K

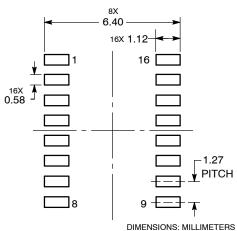


#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD
- PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	1.27 BSC		) BSC
7	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

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